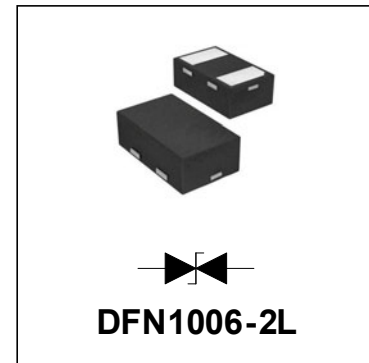


Features

- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- IEC 61000-4-2 $\pm 30\text{kV}$ contact $\pm 30\text{kV}$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 7A (8/20 μs)



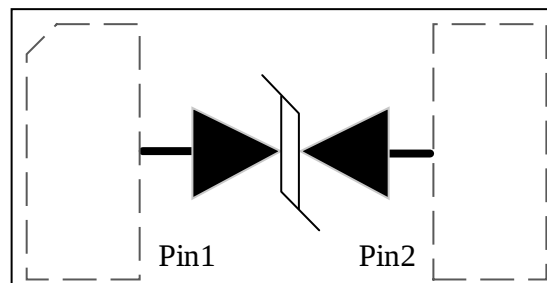
Applications

- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Pagers Peripherals

Mechanical Data

- DFN1006 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration

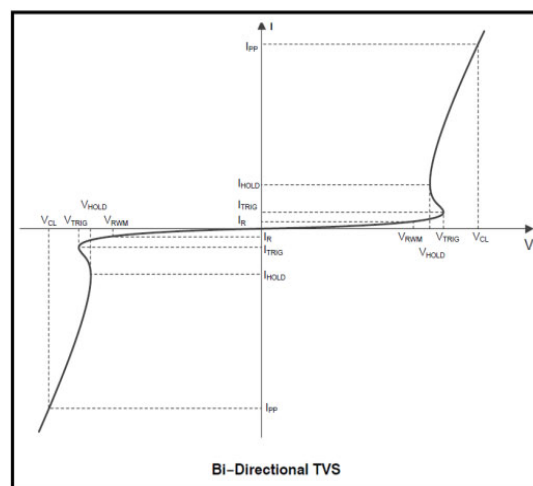


Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	60	Watts
Peak Pulse Current ($t_p = 8/20\mu s$) (note1)	I_{pp}	7	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	30 30	kV
Lead Soldering Temperature	T_L	260(10seconds)	$^{\circ}C$
Junction Temperature	T_J	-55 to + 150	$^{\circ}C$
Storage Temperature	T_{stg}	-55 to + 150	$^{\circ}C$

Electrical Parameters (T=25 $^{\circ}C$)

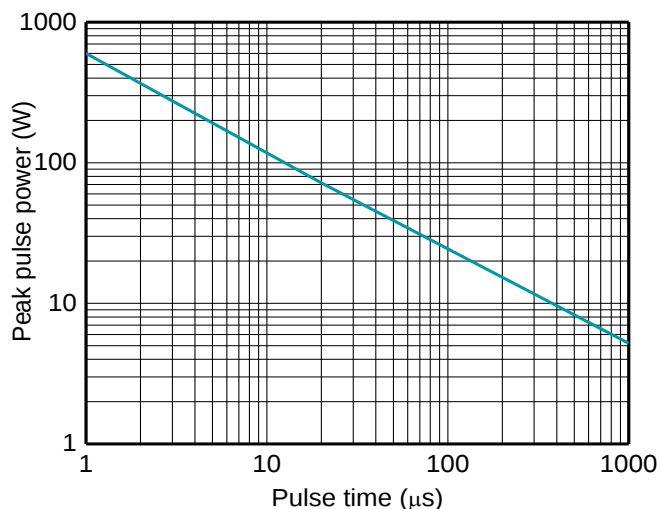
Symbol	Parameter
V_{RWM}	Reverse stand-off voltage
I_R	Reverse leakage current
V_{CL}	Clamping voltage
I_{PP}	Peak pulse current
V_{TRIG}	Reverse trigger voltage
I_{TRIG}	Reverse trigger current
V_{HOLD}	Reverse holding voltage
I_{HOLD}	Reverse holding current



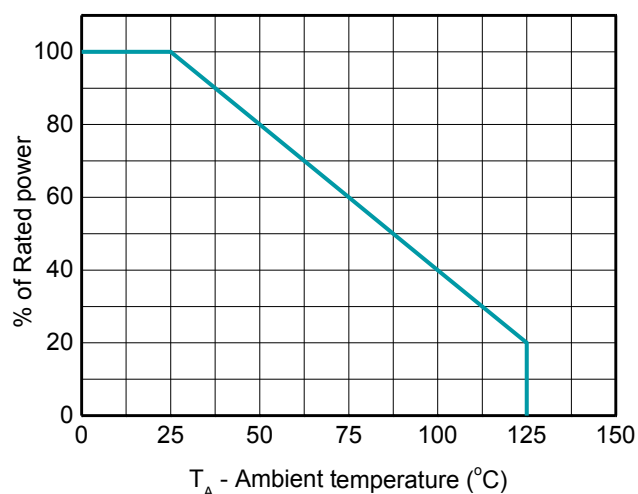
Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				3.3	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	3.5		5	V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3V, T = 25^{\circ}C$			0.1	μA
Clamping Voltage	V_C	$I_{PP} = 7A, t_p = 8/20\mu s$			10	V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$			15	pF

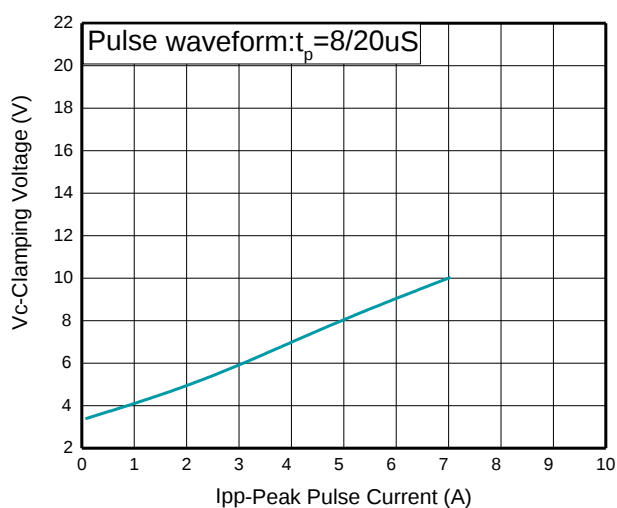
Typical Characteristics



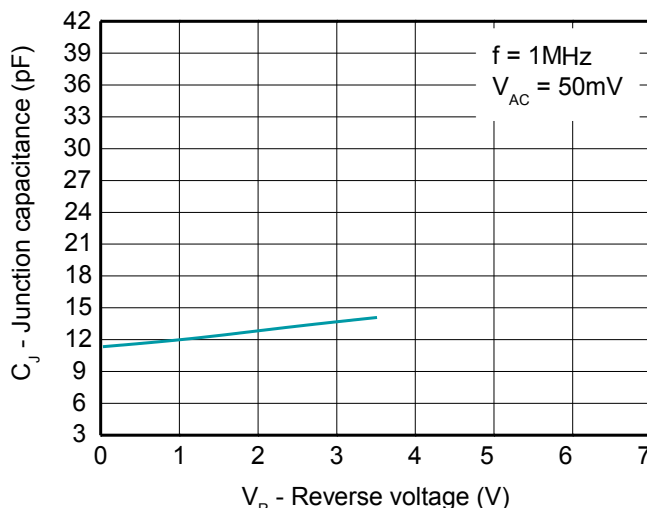
Non-repetitive peak pulse power vs. Pulse time



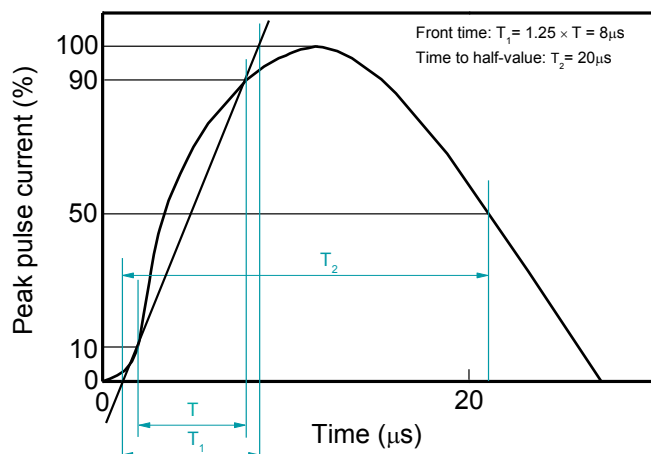
Power derating vs. Ambient temperature



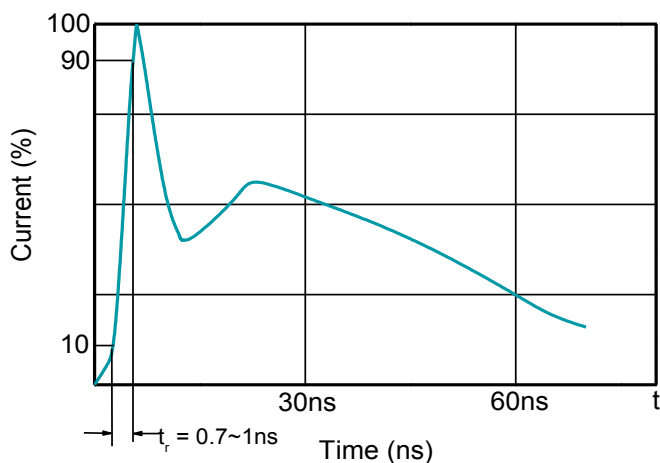
Clamping voltage vs. Peak pulse current



Capacitance vs. Reverse voltage

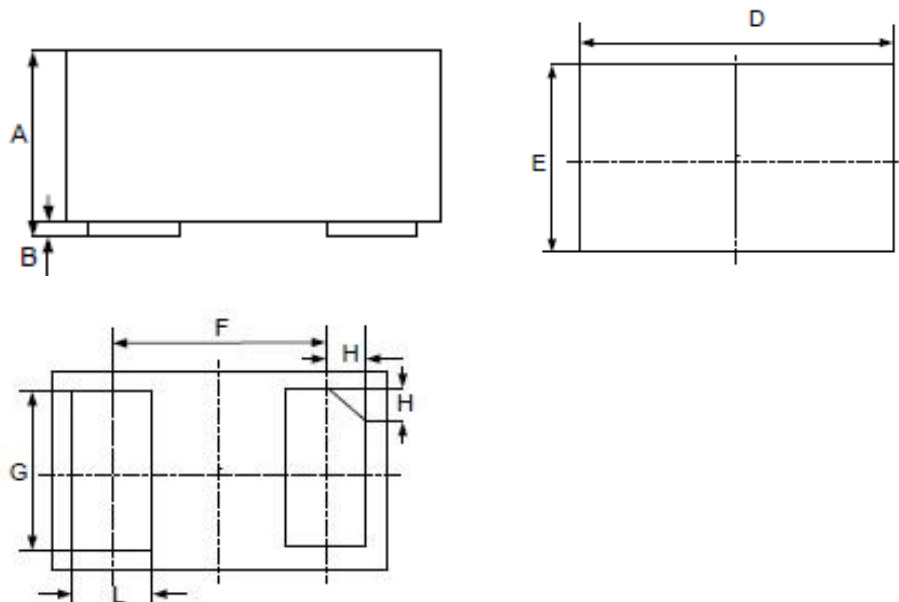


8/20μs waveform per IEC61000-4-5



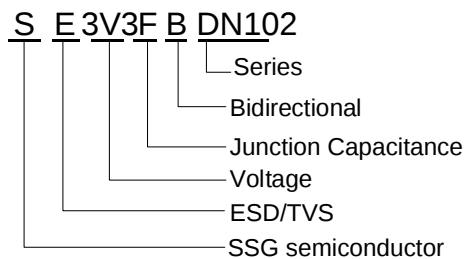
Contact discharge current waveform per IEC61000-4-2

Outline Drawing – DFN1006



DIM	MILIMETER	
	MIN (mm)	MAX (mm)
A	0.34	0.55
B	0	0.05
D	0.95	1.08
E	0.55	0.68
F	0.65(Typ)	
G	0.40	0.60
H	0.07	0.17
L	0.20	0.30

Part Numbering System



Device	Package	Shipping	MarKing	Parameter
SE3V3FBDN102	DFN1006-2L	10000/Tape&Reel	P *	P = Product Code A = Device Code